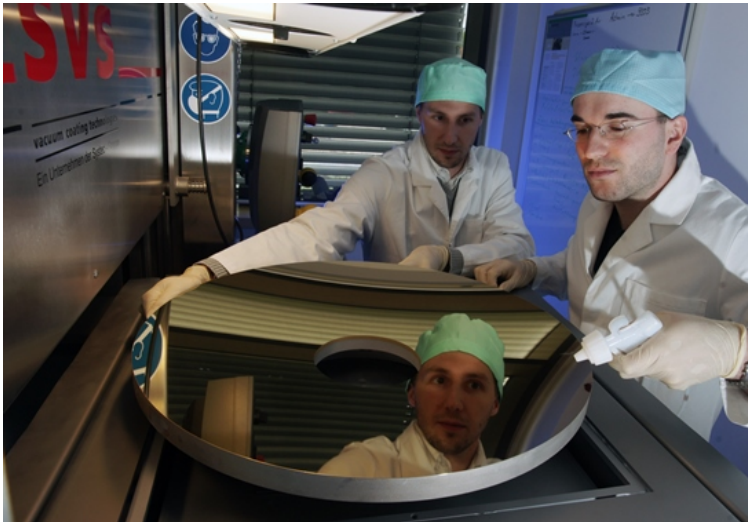

Progress on the Manufacture of Optical Coatings



Norbert Kaiser

Fraunhofer Institute for Applied Optics and
Precision Engineering, Jena, Germany

Workshop Optical Coatings for Laser Applications
11th June 2015
NTB Buchs, Switzerland

09. Juli 1946:

Gründung der Gerätebau-Anstalt in Balzers
durch Fürst Franz Josef II.,
Dr. Max Auwärter und
Emil Georg Bührle





Jones

OUTLINE

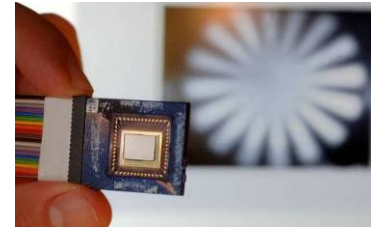
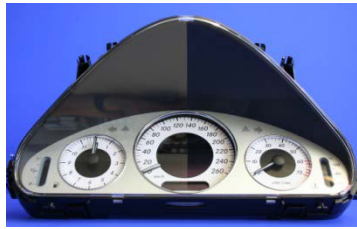
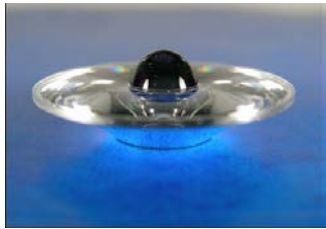
- Markets
- Advanced AR systems
- Space and astro-optics from EUV to IR
- International trends
- Summary



OUTLINE

- **Markets**
- Advanced AR systems
- Space and astro-optics from EUV to IR
- International trends
- Summary

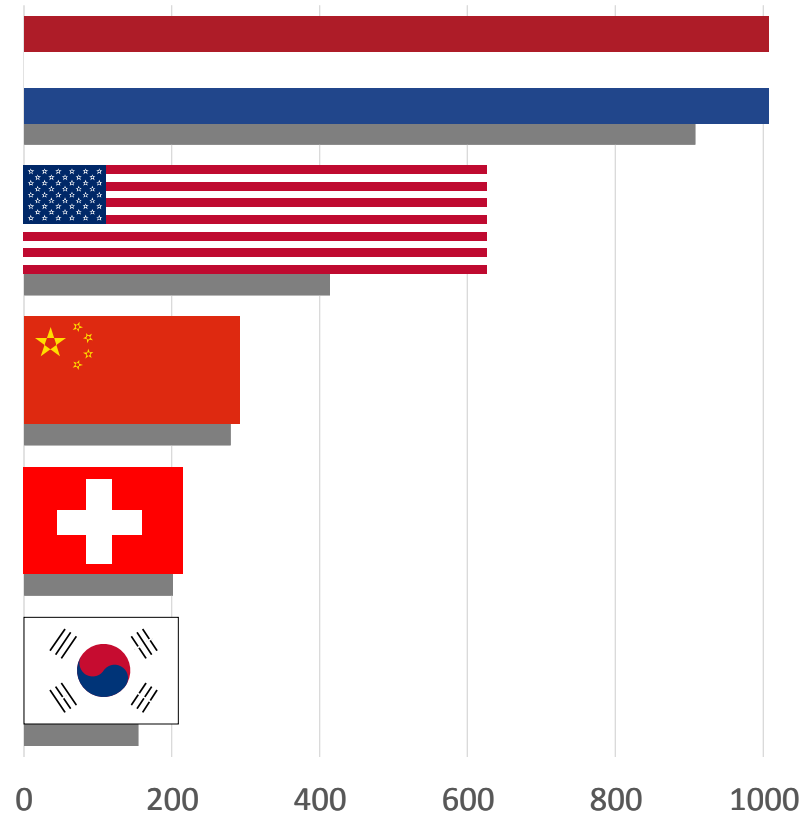
Optical Technology – Key Enabling Technology



Markets

- Production
- Aerospace
- Information
- Medical technology
- Automotive
- Astronomy
- Communication
- Life science
- Illumination
- Security
- Electronics
- Research

EXPORT



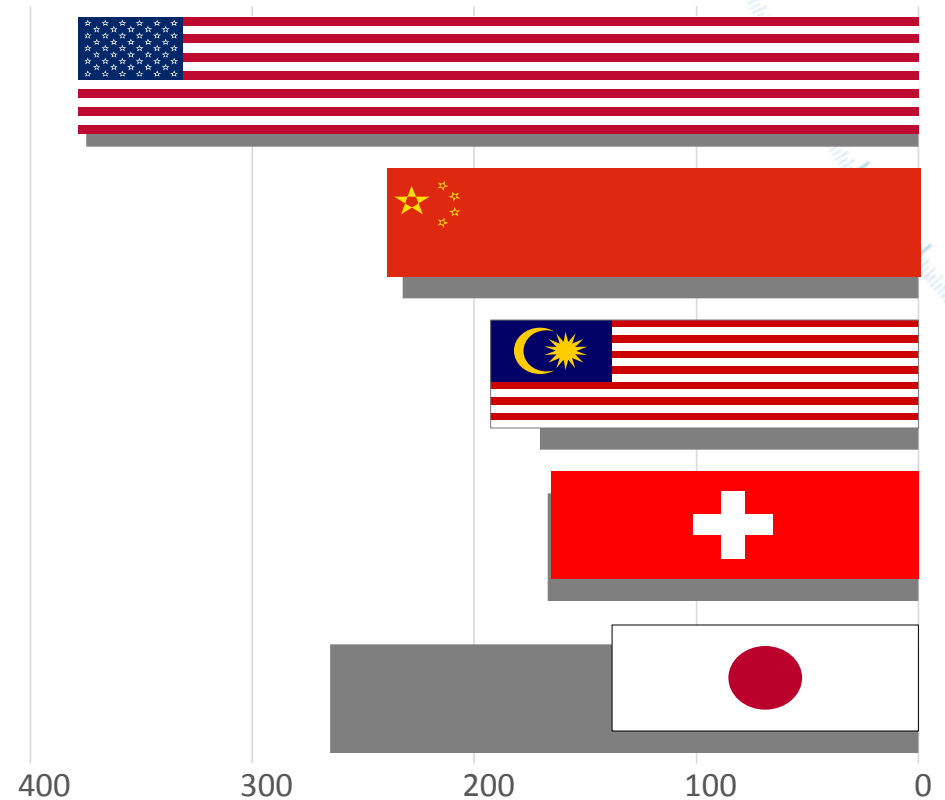
Values in Mio. €

Flags: 2013

■ 2012

Quelle: Statistisches Bundesamt, SPECTARIS

IMPORT Optical Components + Lightsources



Values in Mio. €

Flags: 2013

■ 2012

Quelle: Statistisches Bundesamt, SPECTARIS

OUTLINE

- Markets
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Transparency is a Beautiful Thing - Greta oto

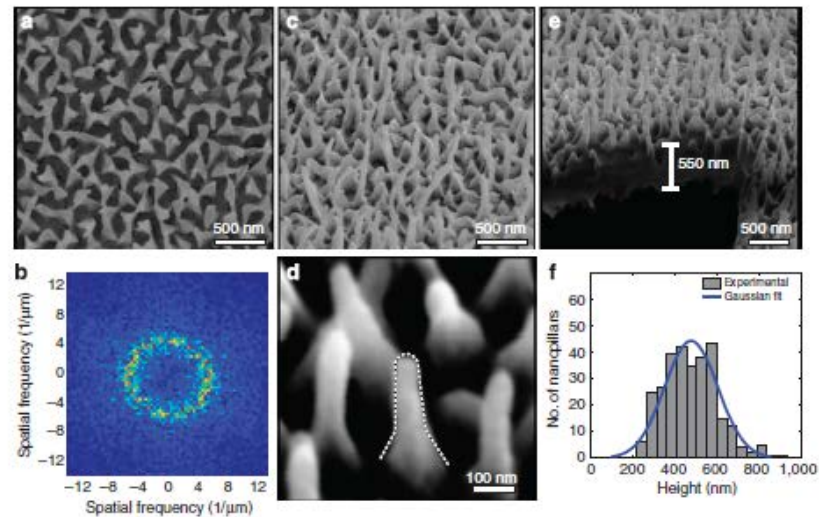
ARTICLE

Received 26 Jun 2014 | Accepted 13 Mar 2015 | Published 22 Apr 2015

DOI: 10.1038/ncomms7909

The role of random nanostructures for the omnidirectional anti-reflection properties of the glasswing butterfly

Radwanul Hasan Siddique¹, Guillaume Gomard² & Hendrik Hölscher¹





Glass Wing Butterfly (Greta oto)

Broadband and wide-angle AR coatings containing organic nanostructured layers



Antireflection coatings with step-down index profile containing plasma-etched organic layers

Ulrike Schulz*, Friedrich Rickelt, Henning Ludwig, Peter Munzert and Norbert Kaiser

Fraunhofer Institute of Applied Optics and Precision Engineering, A.-Einstein-Str. 7, 07745 Jena, Germany

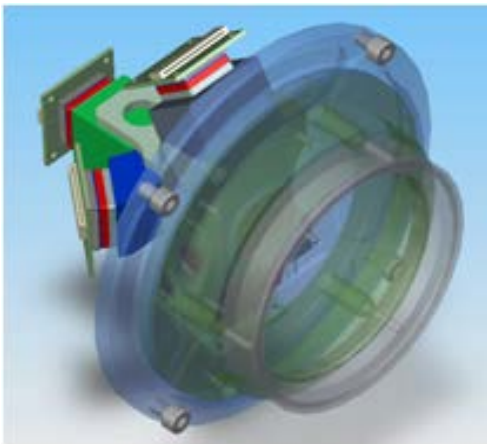
**ulrike.schulz@iof.fraunhofer.de*

Received 20 Mar 2015; revised 21 Apr 2015; accepted 21 Apr 2015; published 4 May 2015

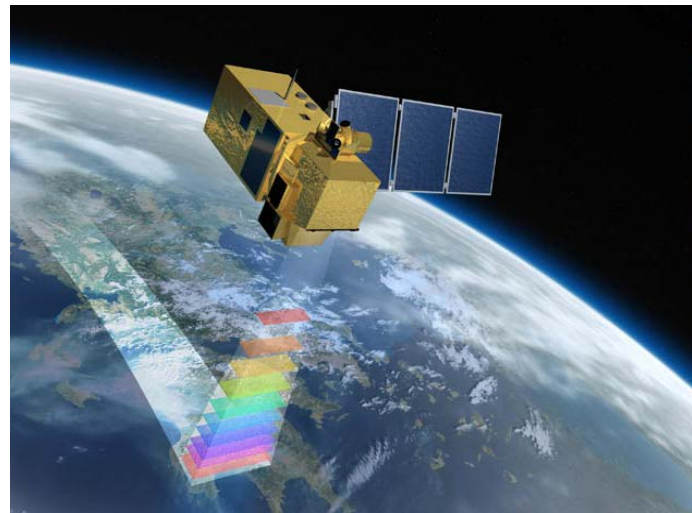
(C) 2015 OSA 1 Jun 2015 | Vol. 5, No. 6 | DOI:10.1364/OME.5.001259 | OPTICAL MATERIALS EXPRESS 1259

Requirements for broadband antireflection

- Enhanced spectral ranges UV- VIS -NIR
- Broad range of light incidence angles
- Camera systems containing curved lenses



Multispectral- camera

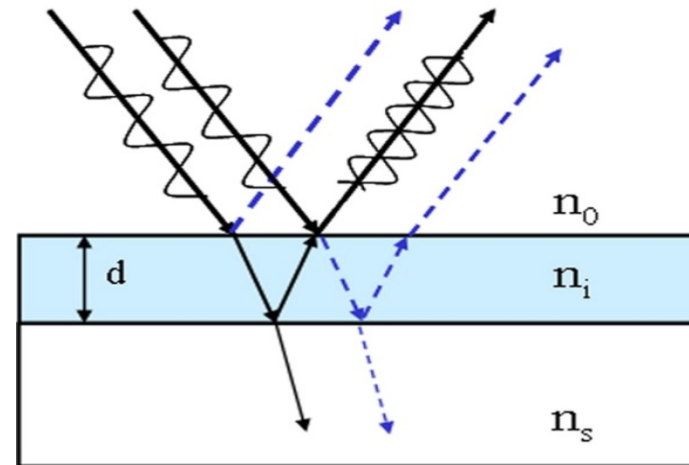


Picture: © Astrium

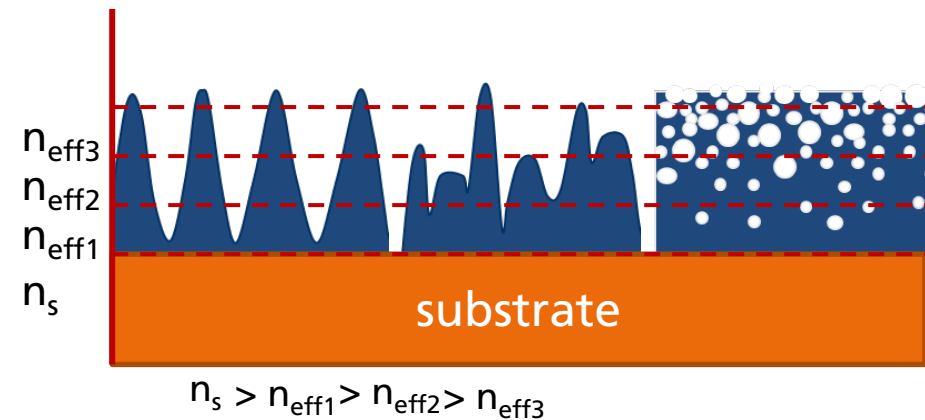


Principles to achieve AR properties

- interference coatings
→ destructive interference

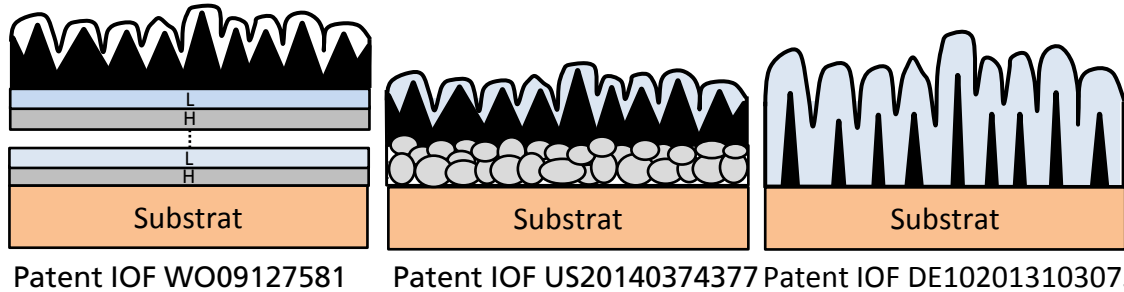


- nanostructures
→ effective medium
→ low „effective“
refractive index n

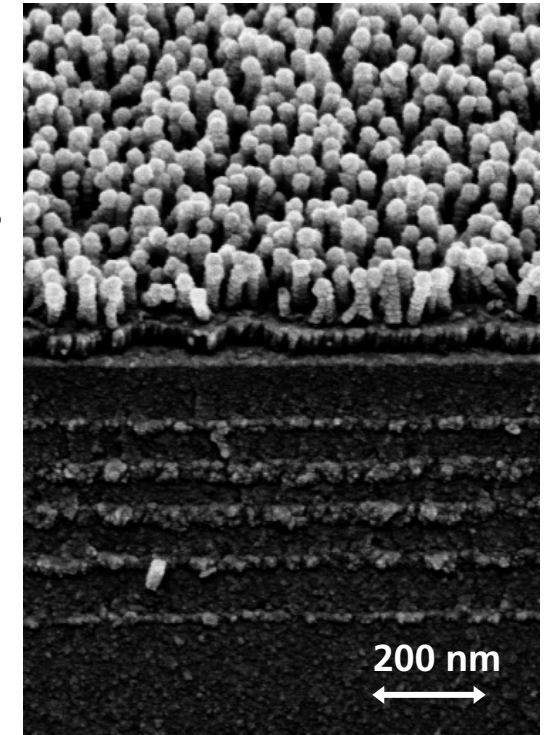
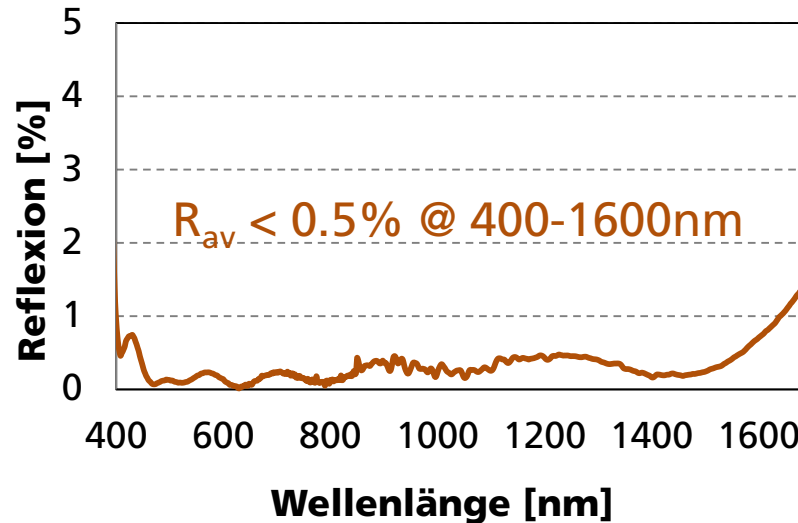


BMBF-Verbundprojekt FIONA (2012-2015)

- Ziel: Farbneutrale Interferenzschichten zur Entspiegelung unter Berücksichtigung organischer Nanostrukturen
- Ergebnis: Verschiedene Systeme mit ausgezeichneter Entspiegelungswirkung

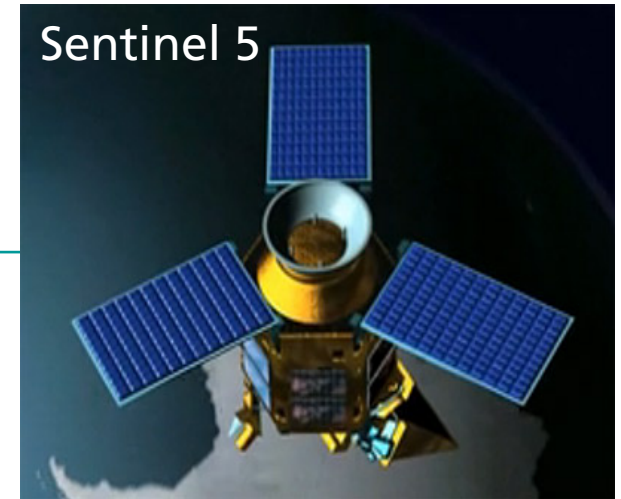


- Beispiel:



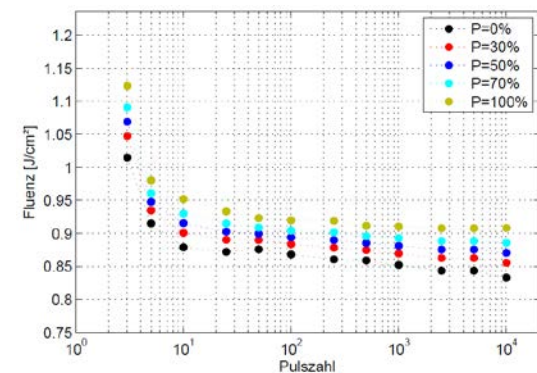
OUTLINE

- Markets
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Metall-dielektrische Schichten für Scanspiegel für Ultrakurzpulslaser

- **Metallspiegel:**
technisch und wirtschaftlich attraktive Lösung für Scanspiegel
- **Hohe Oberflächenqualität
NiP-Schicht, Diamantbearbeitung
und Politur:**
Hochfrequenzrauheit < 0,2 nm rms
- **Metall-dielektrische Schicht:**
qualifiziert für Anwendung in Laserscannern
- **Laserzerstörungsschwelle (LIDT):**
> 0.8 J/cm² @ 1030 nm, 425 fs, AOI 45°



applied optics

Description of particle induced damage on protected silver coatings

STEFAN SCHWINDE,^{1,2,*} MARK SCHÜRMAN,¹ PAUL JOHANNES JOBST,^{1,2}
NORBERT KAISER,¹ AND ANDREAS TÜNNERMANN^{1,2}

¹Fraunhofer-Institute for Applied Optics and Precision Engineering IOF, Albert-Einstein-Straße 7, 07745 Jena, Germany

²Friedrich-Schiller-University Jena, Institute of Applied Physics, Abbe Center of Photonics, Albert-Einstein-Straße 15, D-07745 Jena, Germany

*Corresponding author: stefan.schwinde@iof.fraunhofer.de

Received 24 March 2015; revised 28 April 2015; accepted 28 April 2015; posted 28 April 2015 (Doc. ID 236643); published 21 May 2015

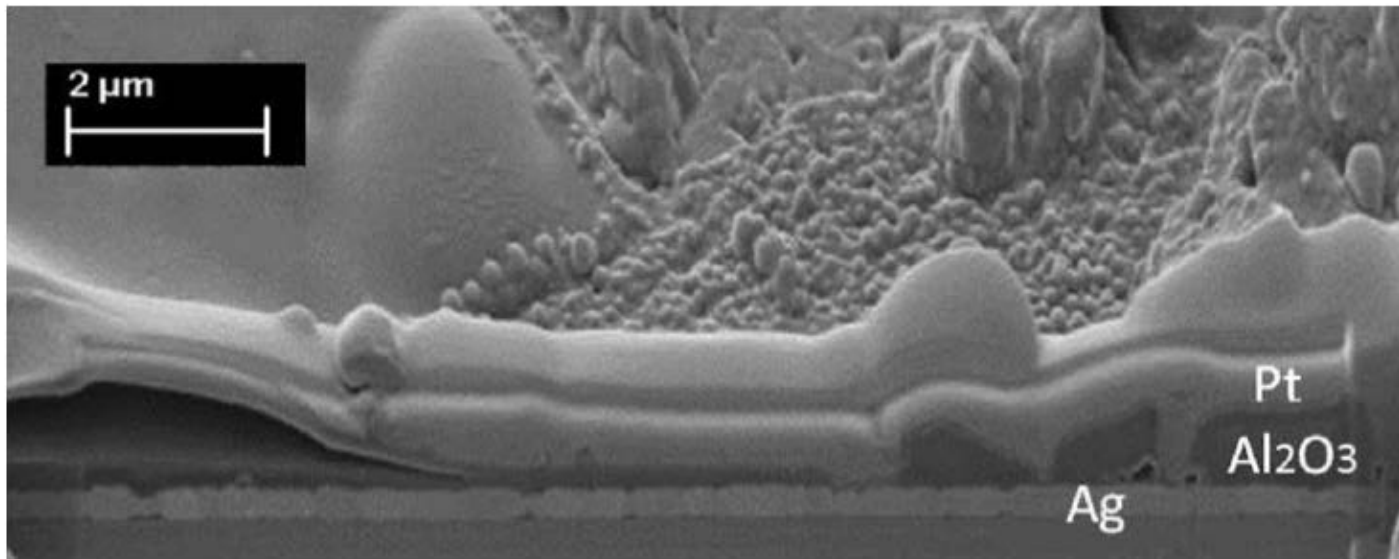
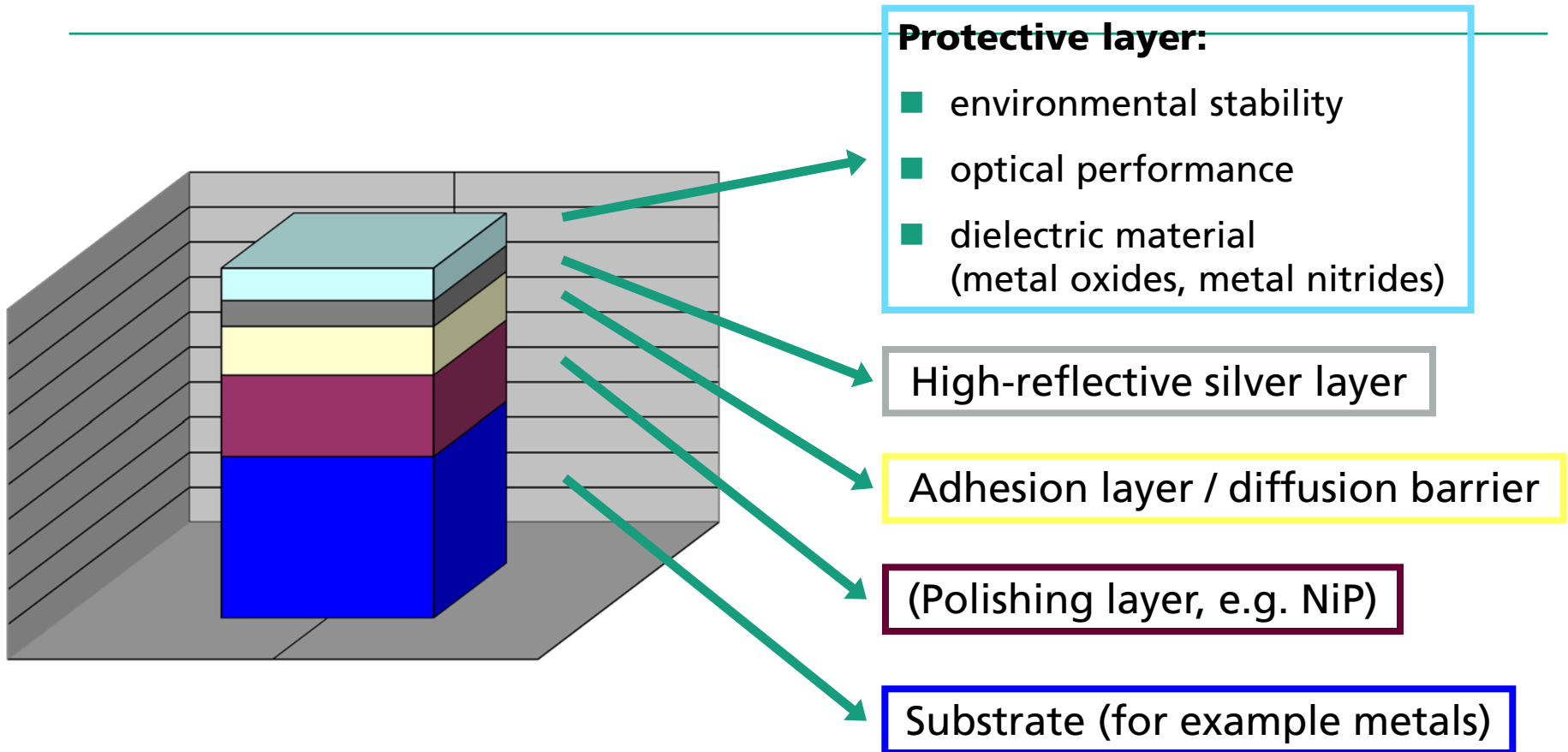
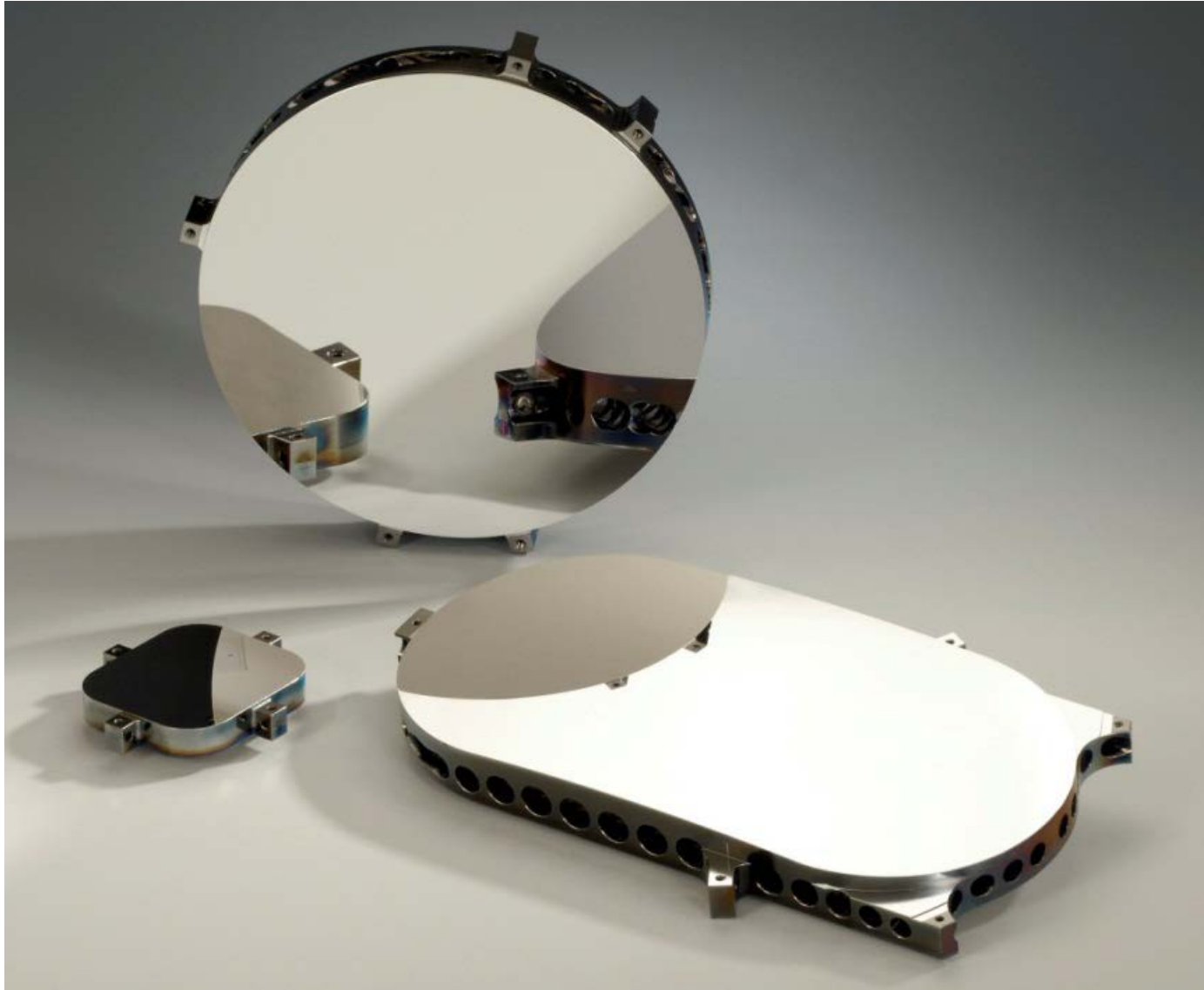


Fig. 2. Cross section of the surrounding area of a particle in the center of a defect in a protected Ag coating. Preparation by FIB and imaging by SEM.

Composition of protected silver coating

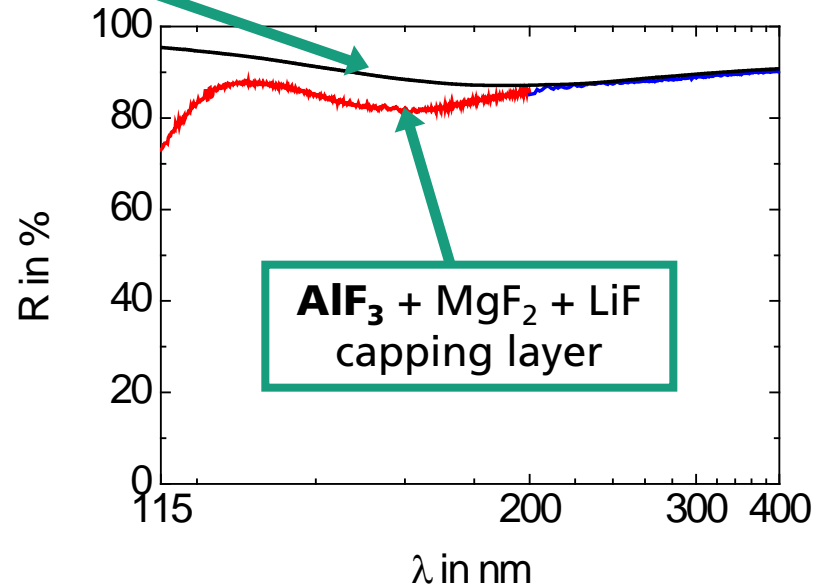
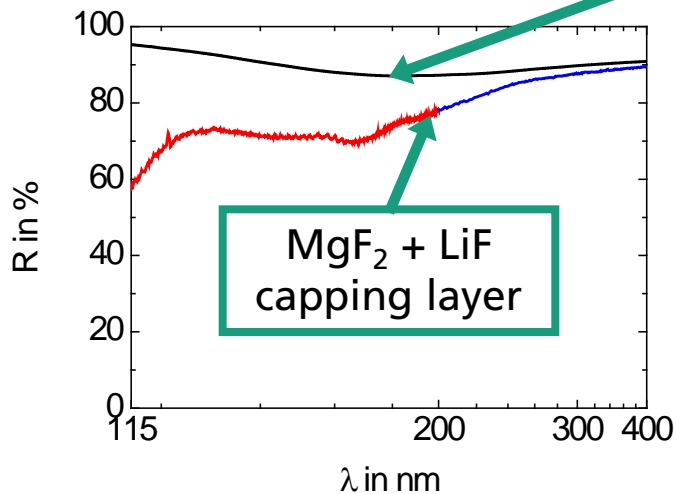




DUV and VUV – 120 nm -> 400 nm

Aluminum reflectors

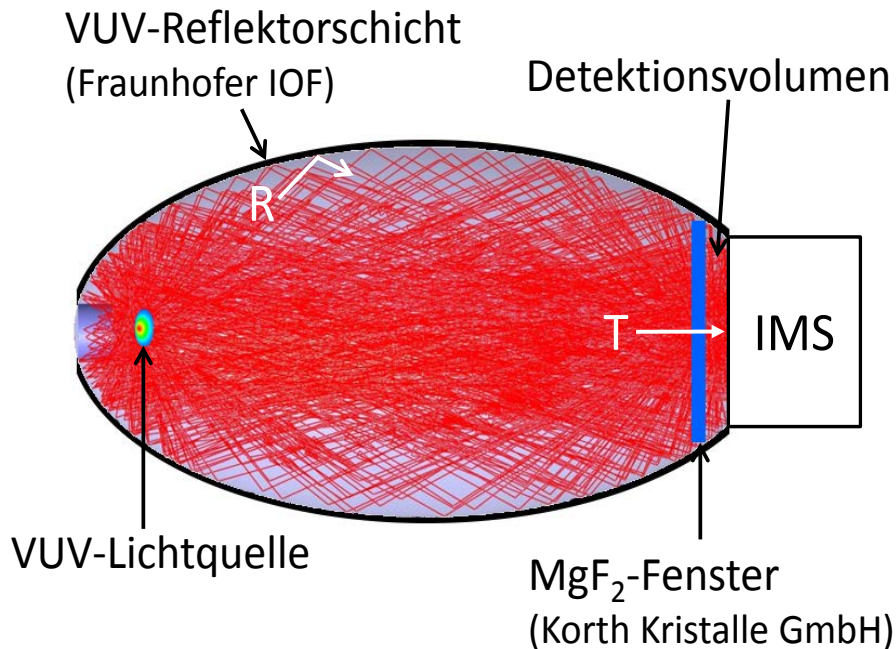
Theoretical reflectivity of bare aluminum



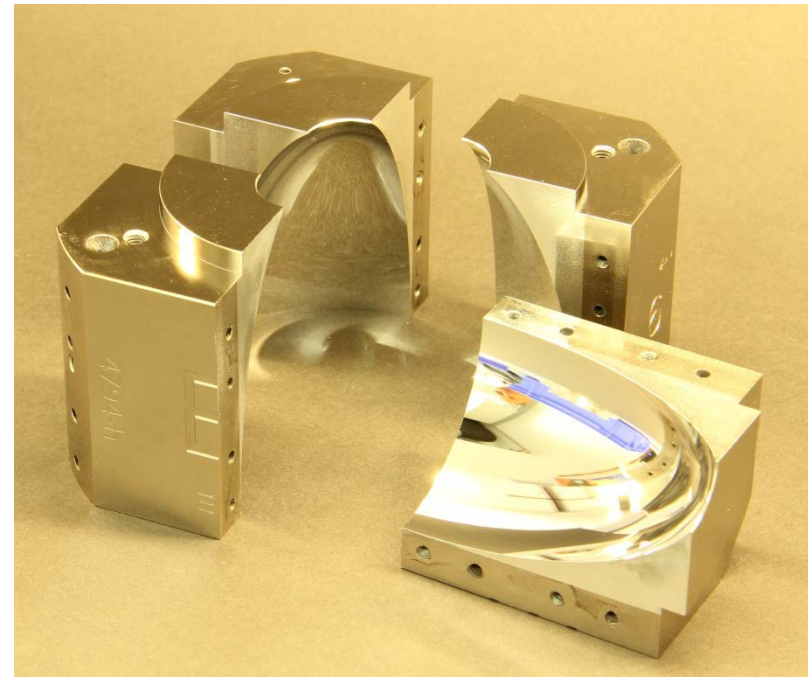
Increased reflectivity due to addition of AlF₃ to capping layer system

Kompetenz VUV-Reflektorbeschichtung: Multipass-Reflexionszelle für DIVE

Prinzip



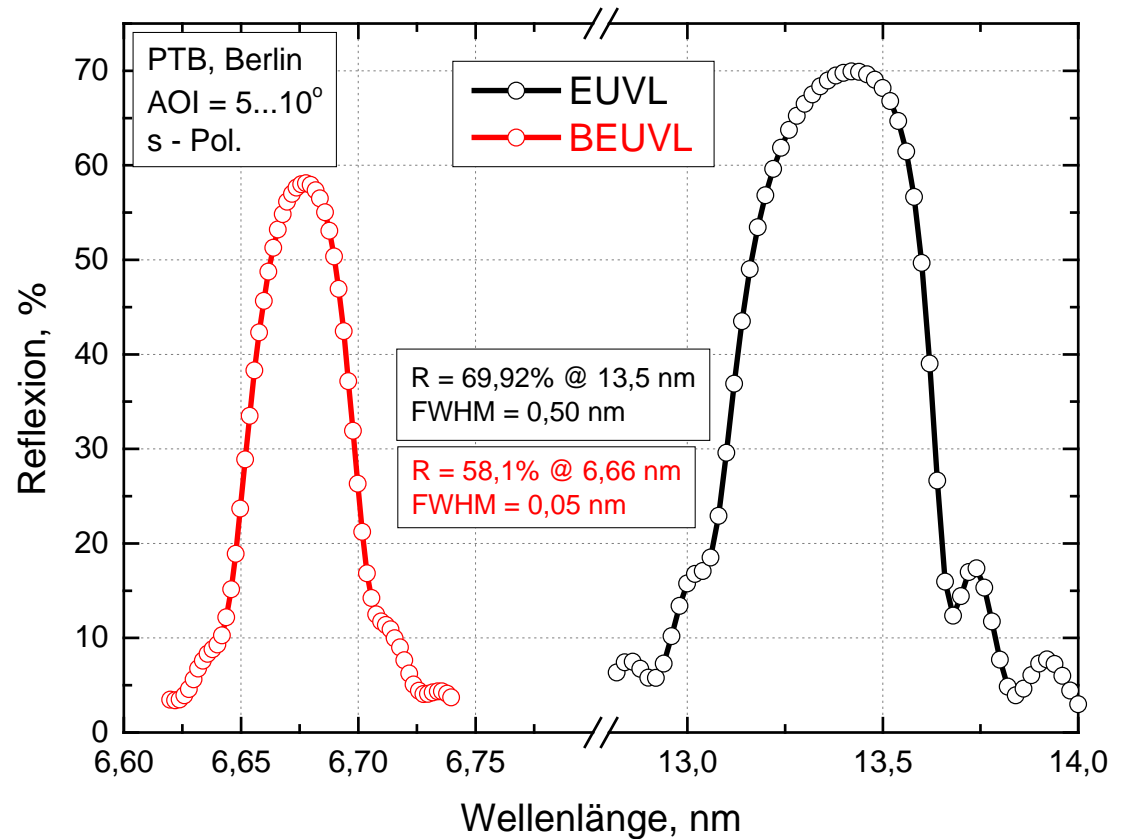
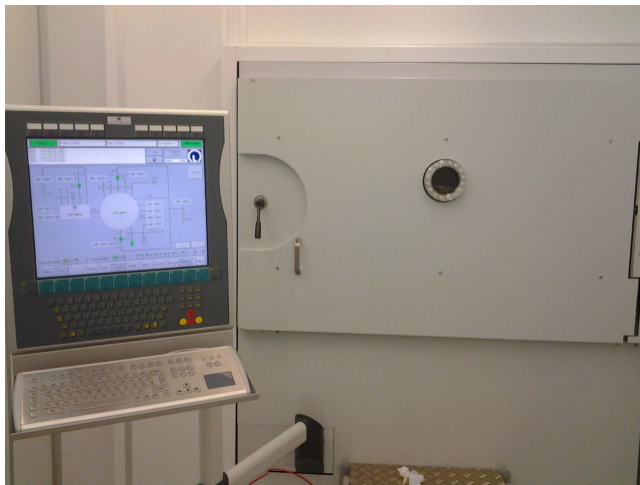
praktische Umsetzung



Beschichtung hochreflektierender Spiegel für EUV/BEUV Lithographie

Beschichtungsanlage Nessy-3:

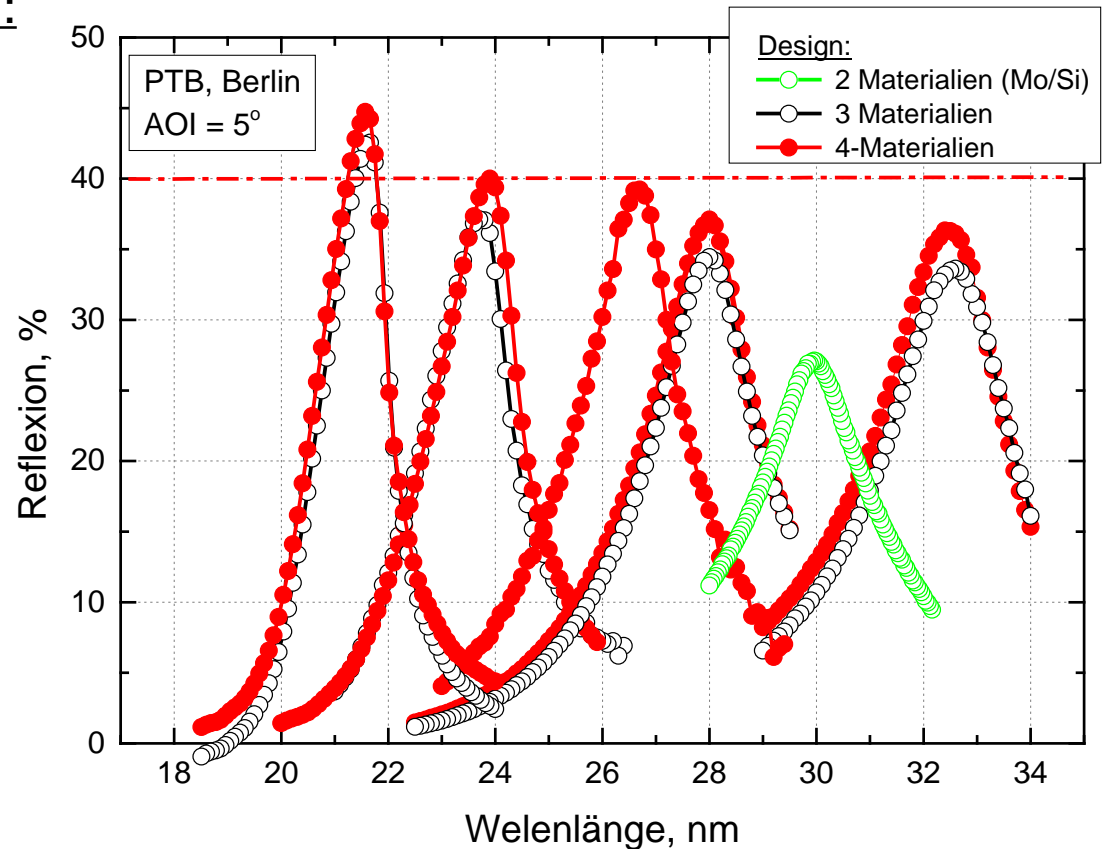
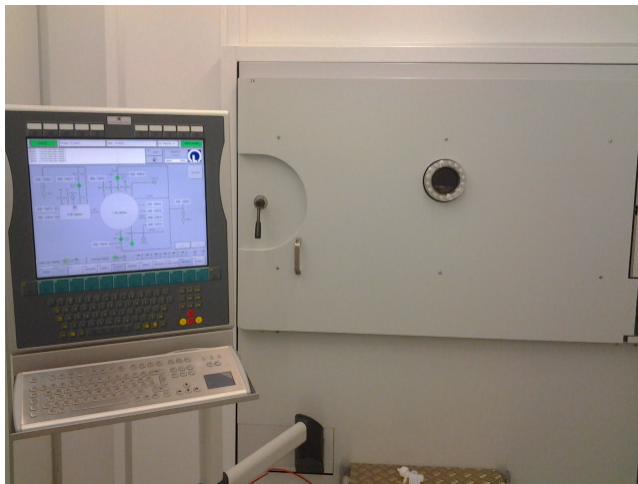
- in Betrieb seit Ende 2013
- Substrate bis \varnothing 200 mm
- Metallschichten & dielektrische Schichten



Beschichtung hochreflektierender Spiegel für EUV/BEUV Lithographie

Beschichtungsanlage Nessy-3:

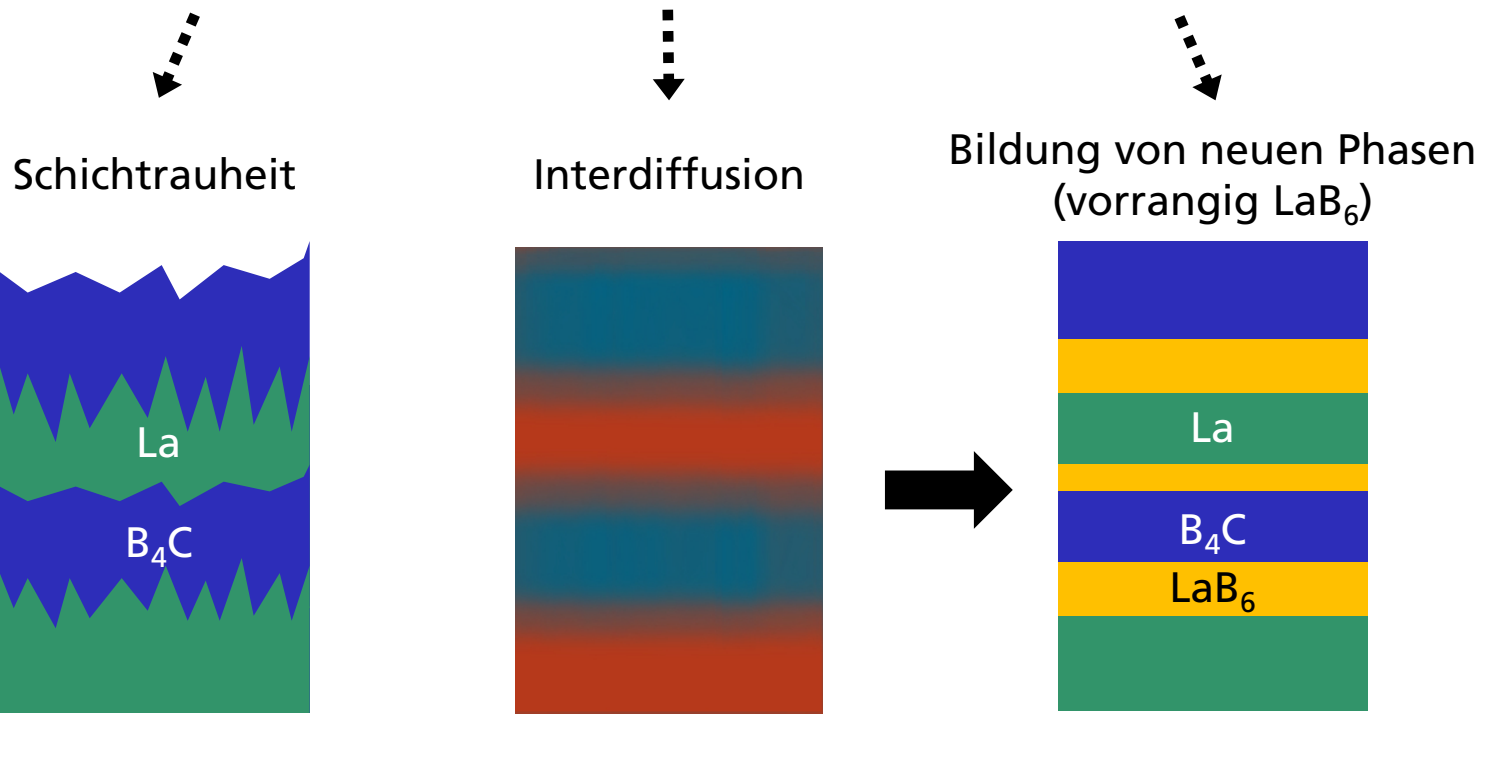
- in Betrieb seit Ende 2013
- Substrate bis \varnothing 200 mm
- Metallschichten & dielektrische Schichten



Ergebnisse

Grenzflächenbeschaffenheit in La/B₄C Multilayern

- Grenzflächen in La/B₄C Multilayern sehr breit ($\sigma \approx 0,6 - 0,8 \text{ nm}$)

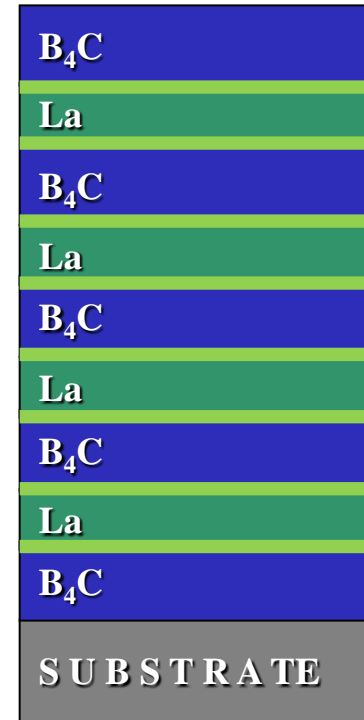
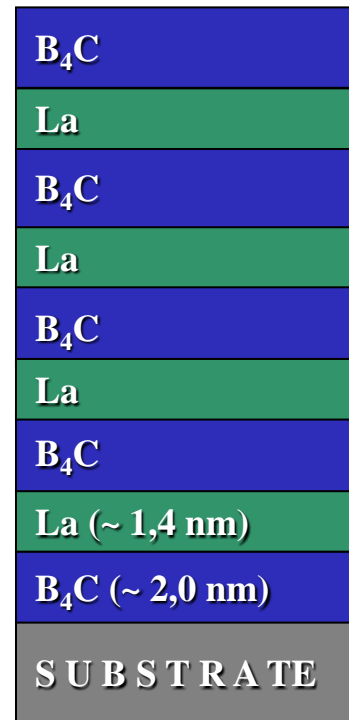
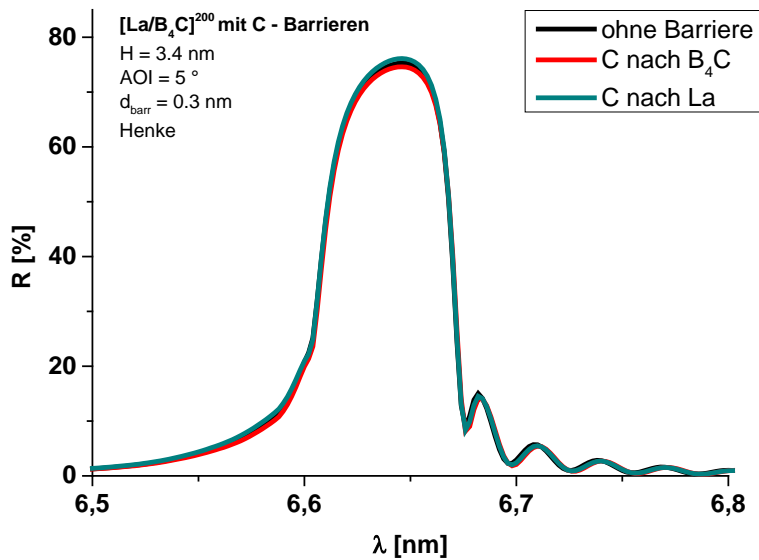


Ergebnisse

Anwendung ultradünner Diffusionsbarrieren

- ultradünne C-Barrieren an Grenzflächen

- Dicke: $d_{\text{barr}} = 0,3 \text{ nm}$



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Physical insight toward electric field enhancement at nodular defects in optical coatings

Xinbin Cheng,^{1,2,3} Abudusalamu Tuniyazi,^{1,2} Zeyong Wei,¹ Jinlong Zhang,^{1,2} Tao Ding,^{1,2}
Hongfei Jiao,^{1,2} Bin Ma,^{1,2} Hongqiang Li,¹ Tongbao Li,^{1,2} and Zhanshan Wang^{1,2,3,*}

¹MOE Key Laboratory of Advanced Micro-Structured Materials, Shanghai, 200092, China

²Institute of Precision Optical Engineering, School of Physics Science and Engineering, Tongji University, Shanghai, 200092, China

³IFSA Collaborative Innovation Center, Shanghai Jiao Tong University, Shanghai 200240, China
*wangzs@tongji.edu.cn

#231132 - \$15.00 USD Received 17 Feb 2015; revised 18 Mar 2015; accepted 19 Mar 2015; published 27 Mar 2015
© 2015 OSA 6 Apr 2015 | Vol. 23, No. 7 | DOI:10.1364/OE.23.008609 | OPTICS EXPRESS 8609

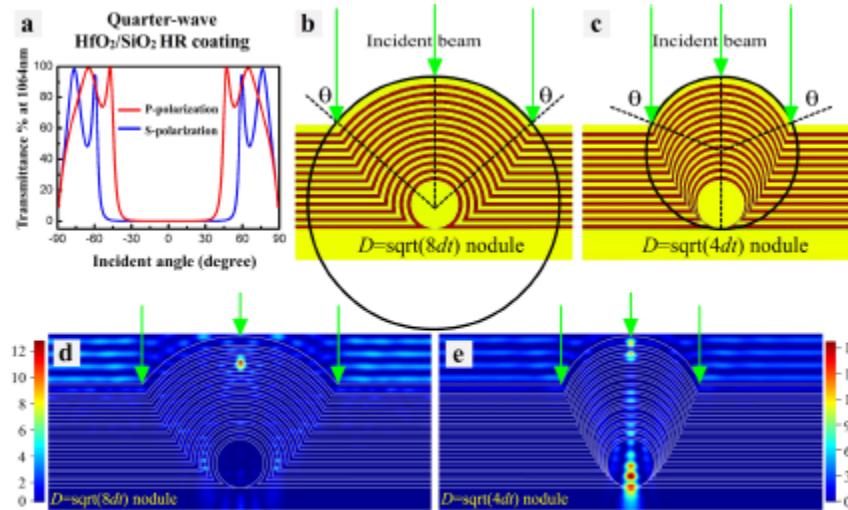


Fig. 1. The $D = \sqrt{8dt}$ and $D = \sqrt{4dt}$ nodules in the quarter-wave $\text{HfO}_2/\text{SiO}_2$ HR coating. (a) P-polarized and S-polarized angular dependent transmission curves of the quarter-wave $\text{HfO}_2/\text{SiO}_2$ HR coating. (b and c) Geometrical modeling of the $D = \sqrt{8dt}$ nodule (b) and the $D = \sqrt{4dt}$ nodule (c). (d and e) FDTD-simulated P-polarized EFI distributions in vicinity of the $D = \sqrt{8dt}$ nodule (d) and the $D = \sqrt{4dt}$ nodule (e). Two nodular geometries show quite different EFI distributions.

Nanosecond laser-induced damage of nodular defects in dielectric multilayer mirrors [Invited]

Xinbin Cheng,^{1,2} Abudusalamu Tuniyazi,^{1,2} Jinlong Zhang,^{1,2} Tao Ding,^{1,2} Hongfei Jiao,^{1,2} Bin Ma,^{1,2} Zeyong Wei,¹ Hongqiang Li,¹ and Zhanshan Wang^{1,2,*}

¹Key Laboratory of Advanced Micro-Structured Materials, Ministry of Education, Shanghai 200092, China

²Institute of Precision Optical Engineering, School of Physics Science and Engineering, Tongji University, Shanghai 200092, China

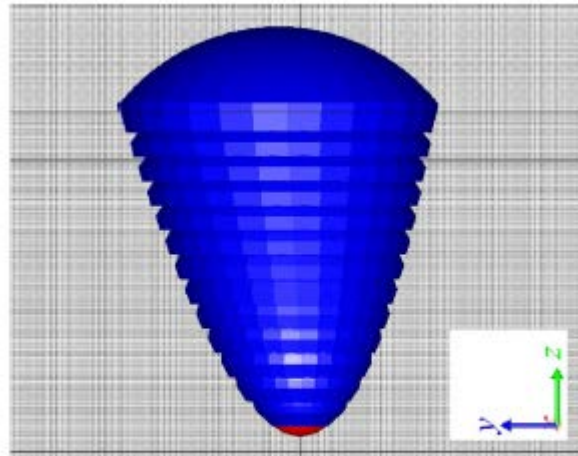


Fig. 6. 3D geometry of an asymmetrical nodule initiating from a 0.9 μm silica microsphere.

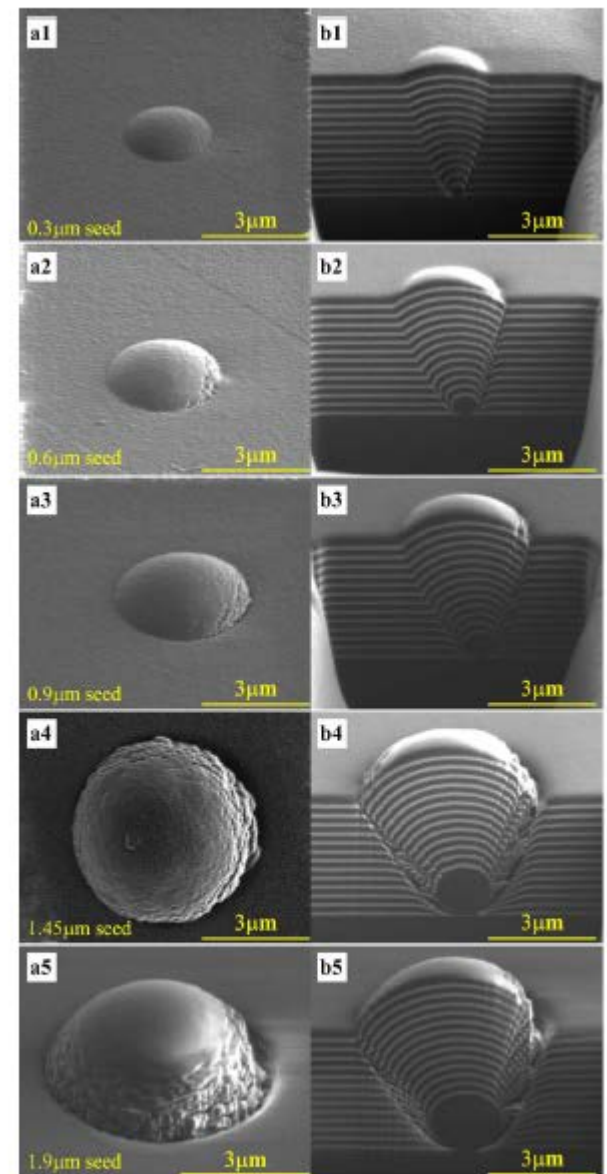
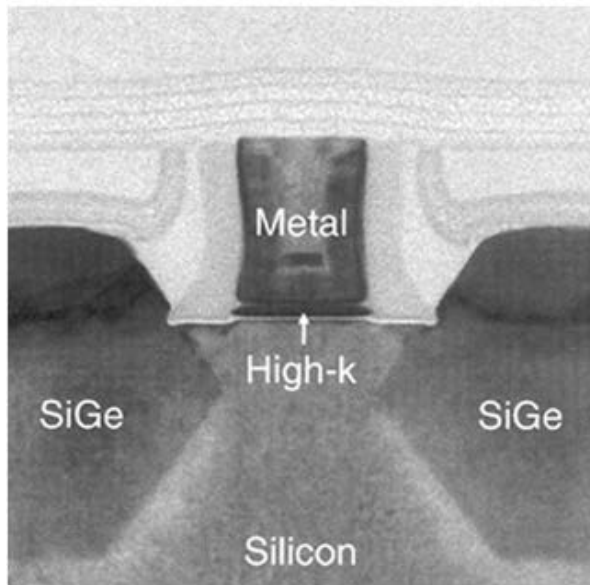
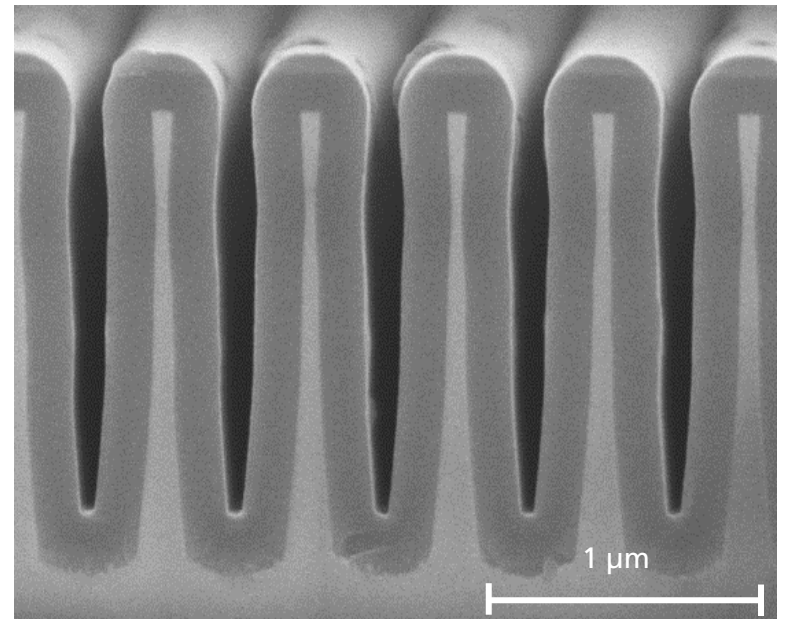


Fig. 5. (a1)–(a5) Top-view micrographs of asymmetrical nodules. (b1)–(b5) Cross-sectional micrographs of the corresponding asymmetrical nodules.

Atomic Layer deposition (ALD)



Intel, 2007



ALD Semiconductor-Industry

⇒ Optical Coatings

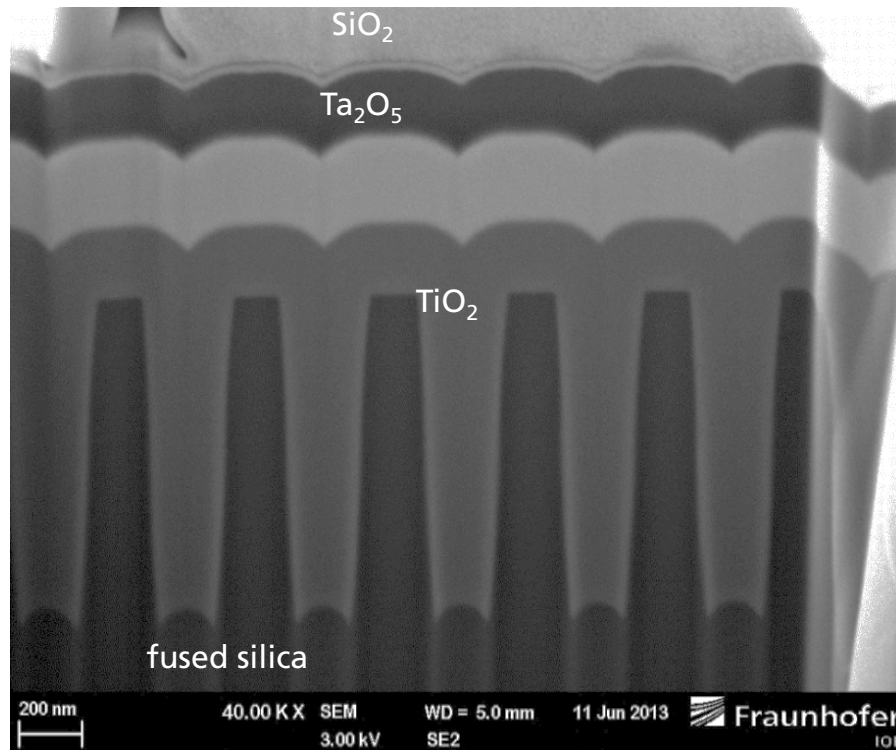
Tuesday, June 24, 11:40 – 12:00 S3-03

Plasma-ALD of SiO₂ layers for optical applications

A. Bingel^{1 2}, L. Ghazaryan¹, S. Ratzsch¹, A. Szeghalmi¹, P. Munzert², U. Schulz², N. Kaiser², A. Tünnermann^{1 2}

¹ Institute of Applied Physics, Abbe Center of Photonics, Friedrich Schiller University [Germany]

² Fraunhofer Institute for Applied Optics and Precision Engineering [Germany]



New Materials

Today, the thin film technology is employed in a wide range of applications. Among the various deposition methods, physical vapor deposition (PVD) and chemical vapor deposition (CVD) processes are widely used in industry. However new processes and/or new materials have to be developed to improve the film properties and to enable synthesis of new materials.

OUTLINE

- Markets
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- International trends
- **Summary**

Recent developments in the field of optical coatings from XUV to IR wavelength

So what does all this add up to?



Leadership in optical thin film plasma-technology is not only a direct key for the development of competitive future concepts and products in optical technology, it also promises a high economical prosperity of the affected industrial companies because of the high net product achievable with optical thin films.

Acknowledgments



MAX-PLANCK-INSTITUT
FÜR QUANTENOPTIK
GARCHING



Acknowledgments



Ulrike Schulz



Sergiy Yulin



Olaf Stenzel



Mark Schürmann

optiXfab.



Torsten Feigl

GEFÖRDERT VOM



Bundesministerium
für Bildung
und Forschung

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Thank you for your attention!